# 112-1 SoC Design Laboratory

## LabD

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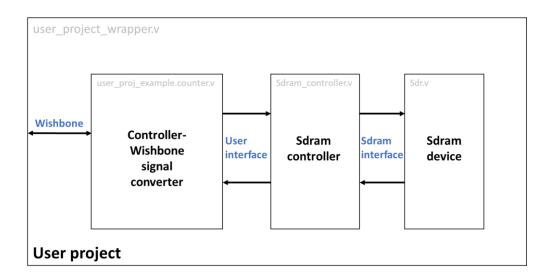
## Introduction

In this lab, we replace the BRAM with SDRAM to store the data and the firmware code. We've done three tasks in this lab: (1) replace the adder with matrix multiplier, (2) add the prefetch function in SDRAM controller, (3) separate data and firmware into two banks in SDRAM.

## **Observations**

## SDRAM controller design and SDRAM bus protocol

## Overall structure



## User interface

There 7 signals in user interface: user\_addr, rw, data\_in, data\_out, busy, in\_valid, out valid. Users can use these signals to read or write to the sdram.

user addr: the address to read/write.

rw: read or write, read is 0 and write is 1.

data in: the data that needs to be written.

data out: the data which is read out by sdram.

in valid: the read/write request.

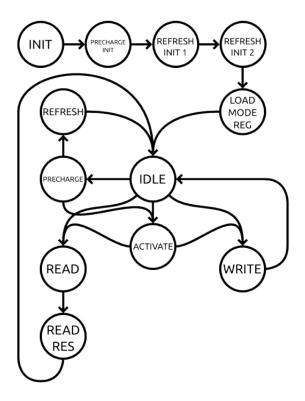
out valid: pulse high when the data to be read out is prepared.

## Sdram interface

The sdram interface contain: sdram\_cle, sdram\_cs, sdram\_cas, sdram\_ras, sdram\_we, sdram\_dqm, sdram\_ba, sdram\_a (address), sdram\_dqi (input data), sdram\_dqo (output data). The interface is controlled by the sdram controller.

## Sdram controller

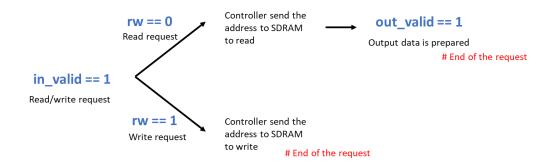
Sdram controller is controlled by the user interface, and the controller will send the address to sdram to fetch or write the data. There's an FSM in the controller:



If the bank that need to be accessed has not been activated, then we need to **activate** before read/write. If we need to change the bank to access, then we need to **precharge** this bank first, **activate** the target bank, then we can do a read/write. If after 750T, all the bank needs to be **precharged** and **refresh**.

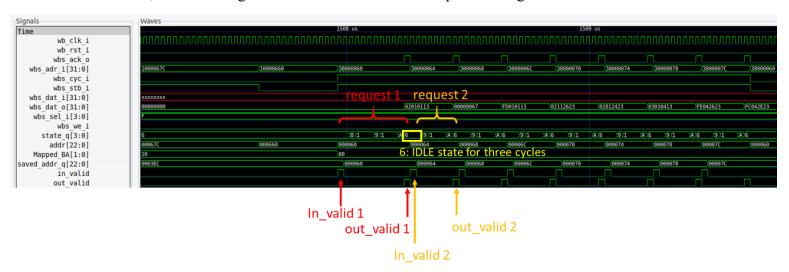
The operation flow in the sdram controller is like below:

## **Operation flow**



## The prefetch scheme

Since the controller will stay in IDLE state for three cycles after sending out the previous data without receiving the next request. We want to reduce the time the controller stays in IDLE state by sending the probable next address to the controller. If the next address matches the address we sent, then we can save two redundant cycles. If not, then we design a scheme to block out the output valid signal.



Our scheme: after request 1, directly load (address 1 + 4) into SDRAM without receiving the next address (address 2). When in\_valid goes high for request 2, we compare (address 1 + 4) with address 2 to check if our preloaded address is correct. If is not correct (miss), then we block out the out\_valid signal to prevent sending out the wrong data.

The signals we use:

**Prefetch**: 1 bit flag, goes high three cycles after in\_valid == 1, goes 0 when there's no input request or output is not valid. If the prefetch is 1, then address + 4 will be load into SDRAM for the next read.

in req: monitor of input read request

```
assign read_req = in_valid & ~rw;
in_req_n = out_valid ? 1'b0 : read_req ? 1'b1 : in_req;
```

**out\_not**: output is not valid. Will be triggered if loaded address is not equal to the new address.

```
out_not_n = out_valid_q ? 1'b0 : (in_valid & addr_flag & (addr != saved_addr_q)) ? 1'b1 : out_not;

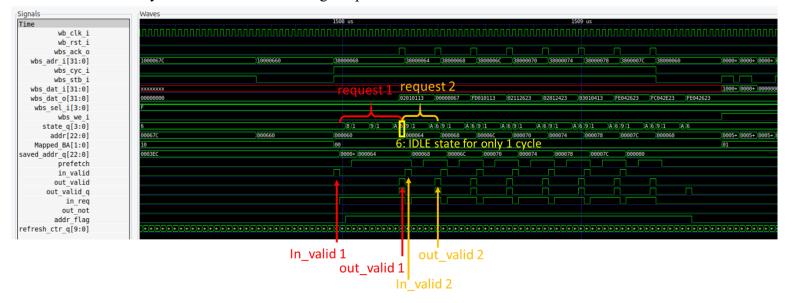
assign out_valid = out_valid_q & !out_not & in_req; 	— Output valid will be blocked by out_not
```

addr\_flag: goes 1 means there's an address sent to SDRAM and waiting for the output data.

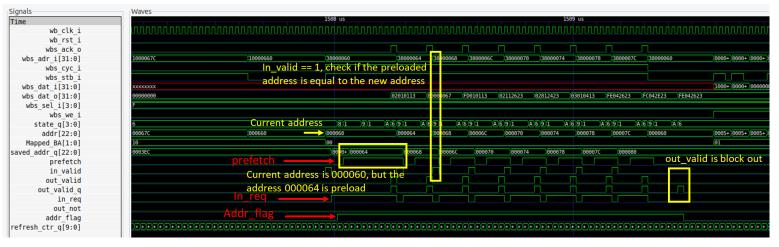
```
addr_flag_n = (in_req & (state_q == IDLE) & !ready_q) ? 1'b1 : out_valid_q ? 1'b0 : addr_flag;

The condition that address was send to SDRAM controller
```

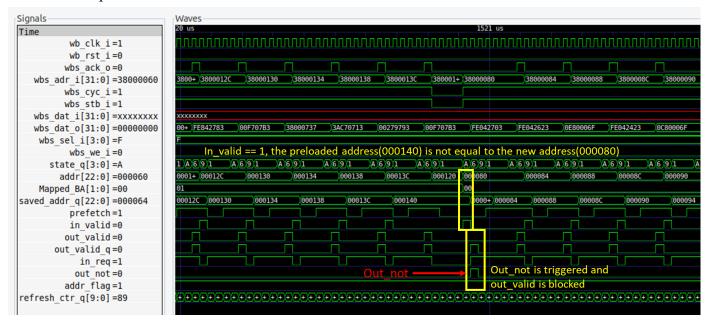
Two cycles are saved after adding the prefetch scheme.



The detail operation of the prefetch scheme.



Example of the miss situation.



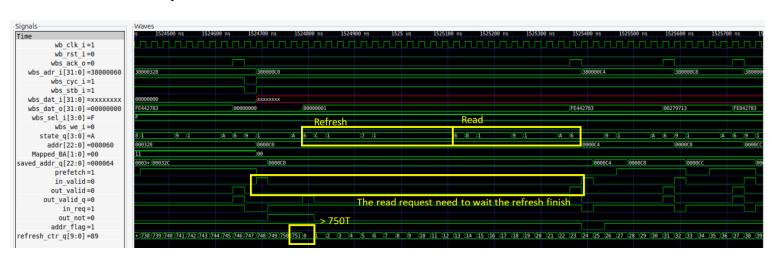
## Modify the linker to load address/data in two different banks

In sections.lds, we modify the address mapping such that the data will be located in  $0x38000300 \sim 0x38000800$  and the firmware code will be located in  $0x38000000 \sim 0x38000300$ . Thus, the data and the code will automatically be located into bank 3 (data) and bank  $0\sim2$  (code).

```
MEMORY {
          vexriscv_debug : ORIGIN = 0xf00f0000, LENGTH = 0x00000100
         dff : ORIGIN = 0x00000000, LENGTH = 0x00000400
         dff2 : ORIGIN = 0x00000400, LENGTH = 0x00000200
         flash : ORIGIN = 0x10000000, LENGTH = 0x01000000
         mprj : ORIGIN = 0x30000000, LENGTH = 0x00100000
         mprjram : ORIGIN = 0x38000000, LENGTH = 0x00000300
         all_data : ORIGIN = 0x38000300, LENGTH = 0x000000500
        hk : ORIGIN = 0x26000000, LENGTH = 0x0010000
         csr : ORIGIN = 0xf00000000, LENGTH = 0x00010000
}
  .data :
          . = ALIGN(8);
          fdata =
         _fdata = .;
*(.data .data.* .gnu.linkonce.d.*)
*(.data1)
         gp = ALIGN(16);
*(.sdata .sdata.* .gnu.linkonce.s.*)
. = ALIGN(8);
 _edata = .;
} > all_data_AT > flash
  .bss :
 {
          . = ALIGN(8);
         _fbss = .;
*(.dynsbss)
         *(.sbss .sbss.* .gnu.linkonce.sb.*)
         *(.scommon)
         *(.dvnbss)
         *(.bss .bss.* .gnu.linkonce.b.*)
         *(COMMON)
         . = ALIGN(8):
 _ebss = .;
_end = .;
} > all_data AT > flash
  .mprjram :
           = ALIGN(8);
         _{fsram} = .;
 } > mpriram AT > flash
```

# Observe SDRAM access conflicts with SDRAM refresh (reduce the refresh period)

When the cycle > 750T:

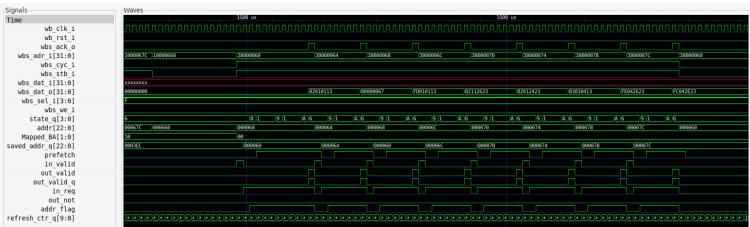


# **Implementation results**

Replace the adder with the matrix multiplier

```
ubuntu@ubuntu2004:~/course-lab_D/lab-sdram/testbench/counter_la$ source run_sim
Reading counter_la.hex
counter_la.hex loaded into memory
Memory 5 bytes = 0x6f 0x00 0x00 0x0b 0x13
VCD info: dumpfile counter_la.vcd opened for output.
LA Test 1 started
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x003e
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x0044
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x004a
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x0050
LA Test 2 passed
```





## Add the prefetch scheme and bank interleave

```
ubuntu@ubuntu2004:~/course-lab_D/lab-sdram/testbench/counter_la$ source run_sim
Reading counter_la.hex
counter_la.hex loaded into memory
Memory 5 bytes = 0x6f 0x00 0x00 0x0b 0x13
VCD info: dumpfile counter_la.vcd opened for output.
LA Test 1 started
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x003e
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x0044
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x0044
Call function matmul() in User Project BRAM (mprjram, 0x38000000) return value passed, 0x0050
LA Test 2 passed
```



